LM2900, LM3900 QUADRUPLE OPERATIONAL AMPLIFIERS

D2531, JULY 1979-REVISED SEPTEMBER 1990

- Wide Range of Supply Voltages, Single or Dual Supplies
- Wide Bandwidth
- Large Output Voltage Swing
- Output Short-Circuit Protection
- Internal Frequency Compensation
- Low Input Bias Current
- Designed to be Interchangeable with National Semiconductor LM2900 and LM3900, Respectively

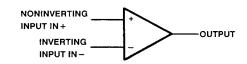
description

These devices consist of four independent, highgain frequency-compensated Norton operational amplifiers that were designed specifically to operate from a single supply over a wide range of voltages. Operation from split supplies is also possible. The low supply current drain is essentially independent of the magnitude of the supply voltage. These devices provide wide bandwidth and large output voltage swing.

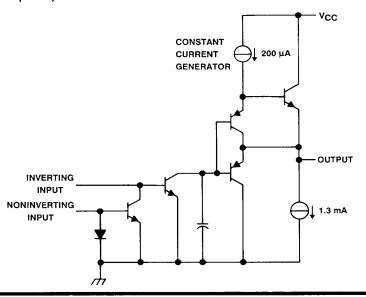
The LM2900 is characterized for operation from -40°C to 85°C , and the LM3900 is characterized for operation from 0°C to 70°C .

N PACKAGE (TOP VIEW) #1 IN+ 1 1 14 VCC #2 IN + ∏2 13 7 #3 IN+ #2 IN - 3 12 #4 IN+ #2 OUT 4 11 #4 IN-#1 OUT **□**5 10 #4 OUT 🛚 #3 ООТ #1 IN - 16 9 8 #3 IN -GND [7

symbol (each amplifier)



schematic (each amplifier)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

	LM2900	LM3900	UNIT	
Supply voltage, VCC (see Note 1)	36	36	V	
Input current	20	20	mA	
Duration of output short circuit (one amplifier) to ground at (or below) 25°C free-air temperature (see Note 2)	unlimited	unlimited		
Continuous total dissipation	See Dissipation Rating Table			
Operating free-air temperature range	-40 to 85	0 to 70	°C	
Storage temperature range	-65 to 150	-65 to 150	°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260	260	°C	

- NOTES: 1. All voltage values, except differential voltages, are with respect to the network ground terminal.
 - 2. Short circuits from outputs to $\mbox{V}_{\mbox{\footnotesize{CC}}}$ can cause excessive heating and eventual destruction.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE TA = 25°C	TA = 70°C POWER RATING	T _A = 85°C POWER RATING
N	1150 mW	9.2 mW/°C	736 mW	598 mW

recommended operating comditions

	LM2	LM2900		LM3900	
	MIN	MAX	MIN	MAX	UNIT
Supply voltage, V _{CC} (single supply)	4.5	32	4.5	32	V
Supply voltage, V _{CC+} (dual supply)	2.2	16	2.2	16	V
Supply voltage, V _{CC} (dual supply)	-2.2	- 16	-2.2	- 16	V
Input current (see Note 3)		- 1		- 1	mA
Operating free-air temperature, TA	-40	85	0	70	°C

NOTE 3: Clamp transistors are included that prevent the input voltages from swinging below ground more than approximately -0.3 V. The negative input currents that may result from large signal overdrive with capacitive input coupling must be limited externally to values of approximately -1 mA. Negative input currents in excess of -4 mA will cause the output voltage to drop to a low voltage. These values apply for any one of the input terminals. If more than one of the input terminals are simultaneously driven negative, maximum currents are reduced. Common-mode current biasing can be used to prevent negative input voltages.



electrical characteristics, VCC = 15 V, TA = 25 °C (unless otherwise noted)

PARAMETER		TEST CONDITIONS [†]		LM2900		LM3900			UNIT	
				MIN	TYP	MAX	MIN	TYP	MAX	ONIT
lΒ	Input bias current (inverting input)	I _{I+} = 0	T _A = 25°C T _A = Full range		30 300	200		30 300	200	nA
1 ₁	Mirror gain	$I_{ +} = 20 \mu A \text{ to } 200 \mu A$ $T_A = \text{Full range, See Note 4}$		0.9		1.1	0.9		1.1	μΑ/μΑ
1.	Change in mirror gain				2	5		2	5	%
	Mirror current	V _{I+} = V _{I-} , See Note 4	T _A = Full range,		10	500		10	500	μΑ
AVD	Large-signal differential voltage amplification	V _O = 10 V, f = 100 Hz	$R_L = 10 \text{ k}\Omega$,	1.2	2.8		1.2	2.8		V/mV
rį	Input resistance (inverting input)				1			1		МΩ
ro	Output resistance				8			8		kΩ
В1	Unity-gain bandwidth (inverting input)	•			2.5			2.5		MHz
ksvr	Supply voltage rejection ratio (ΔVCC/ΔVIQ)				70			70		dB
		$ \begin{aligned} I_{1+} &= 0, \\ I_{1-} &= 0 \end{aligned} $	$R_L = 2 k\Omega$	13.5			13.5			
Vон	High-level output voltage		V _{CC} = 30 V, No load		29.5			29.5		V
VOL	Low-level output voltage	$l_{\parallel +} = 0,$ $R_{\perp} = 2 k\Omega$	l ₁ = 10 μA,		0.09	0.2		0.09	0.2	٧
loнs	Short-circuit output current (output internally high)		l _{I -} = 0	-6	- 18		-6	- 10		mA
	Pull-down current			0.5	1.3		0.5	1.3		mA
lOL	Low-level output current [‡]	l ₁₋ = 5 μA,	V _{OL} = 1 V		5			5		mA
lcc	Supply current (four amplifiers)	No load			6.2	10		6.2	10	mA

[†]All characteristics are measured under open-loop conditions with zero common-mode voltage unless otherwise specified. Full range for TA is -40°C to 85°C for LM2900, and 0°C to 70°C for LM3900.

NOTE 4: These parameters are measured with the output balanced midway between VCC and ground.

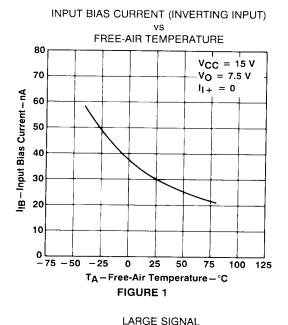
operating characteristics, $VCC \pm = \pm 15 \text{ V}$, $TA = 25 ^{\circ}C$

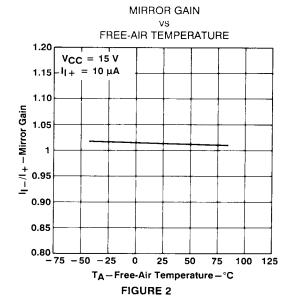
PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
Low-to-high output	VO = 10 V, CL = 100	pF, 0.5	V/μs
SR Slew rate at unit gain High-to-low output	$R_{l} = 2 k\Omega$	20	V/μS



[‡]The output current-sink capability can be increased for large-signal conditions by overdriving the inverting input.

TYPICAL CHARACTERISTICS†





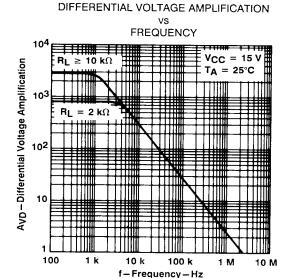
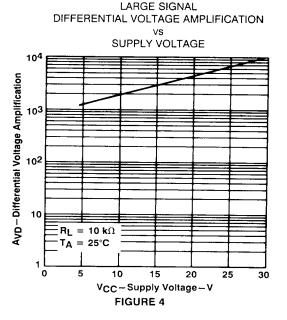


FIGURE 3



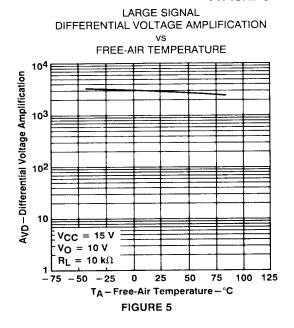
† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

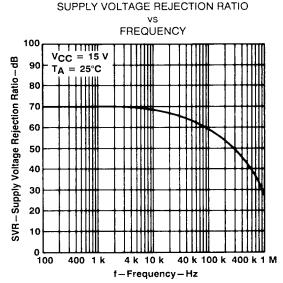


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TYPICAL CHARACTERISTICS[†]

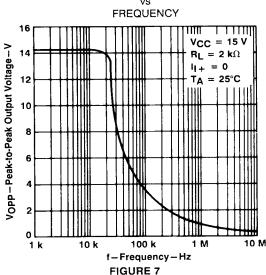


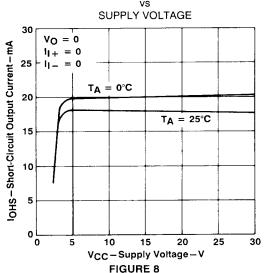


PEAK-TO-PEAK OUTPUT VOLTAGE VS **FREQUENCY** 16



FIGURE 6



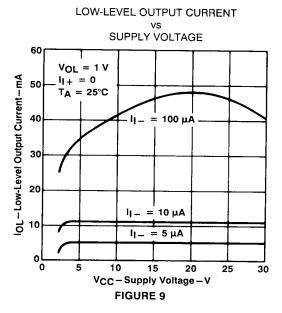


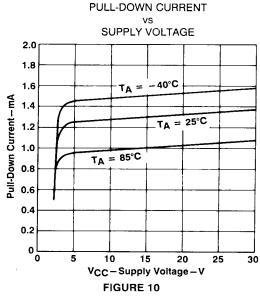
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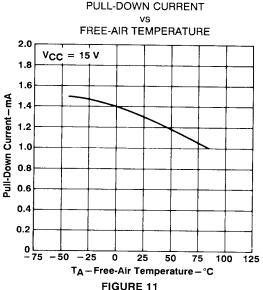


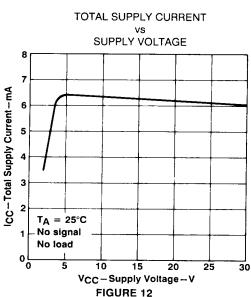
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TYPICAL CHARACTERISTICS†









[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



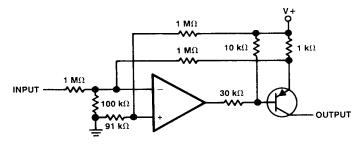
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TYPICAL APPLICATION DATA

Norton (or current-differencing) amplifiers can be used in most standard general-purpose op-amp applications. Performance as a dc amplifier in a single-power-supply mode is not as precise as a standard integrated-circuit operational amplifier operating from dual supplies. Operation of the amplifier can best be understood by noting that input currents are differenced at the inverting input terminal and this current then flows through the external feedback resistor to produce the output voltage. Common-mode current biasing is generally useful to allow operating with signal levels near (or even below) ground.

Internal transistors clamp negative input voltages at approximately -0.3 V but the magnitude of current flow has to be limited by the external input network. For operation at high temperature, this limit should be approximately $-100~\mu\text{A}$.

Noise immunity of a Norton amplifier is less than that of standard bipolar amplifiers. Circuit layout is more critical since coupling from the output to the noninverting input can cause oscillations. Care must also be exercised when driving either input from a low-impedance source. A limiting resistor should be placed in series with the input lead to limit the peak input current. Current up to 20 mA will not damage the device but the current mirror on the noninverting input will saturate and cause a loss of mirror gain at higher current levels, especially at high operating temperatures.



IO ≈ 1 mA per input volt

FIGURE 13. VOLTAGE-CONTROLLED CURRENT SOURCE

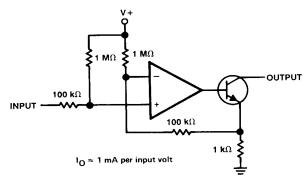


FIGURE 14. VOLTAGE-CONTROLLED CURRENT SINK



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